

**MECHANICAL DATA** 

Polarity: color band denotes cathode end

Case: MiniMELF glass case

Weight: Approx. 0.05 gram

# **BAS285-GS08**

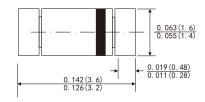
#### SMALL SIGNAL SCHOTTKY DIODES

#### FEATURES

For general purpose applications These diodes features very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges. This diode is also available in the DO-35 glass case with type designation LL85. High temperature soldering guaranteed:260°C/10 seconds at terminals Component in accordance to RoHS 2011/65/EU



MiniMELF



## ABSOLUTE RATINGS(LIMITING VALUES)

	Symbols	Value	Units
Repetitive Peak Reverse Voltage	VR	30	V
Forward Continuous Current at TA=25°C	lF	200 1)	mA
Repetitive Peak Forward Current at t≮ 1s, & 0.5, T₄=25°C	lfм	300 <sup>1)</sup>	mA
Surge forward current at $t_p$ <10ms , TA=25 °C	IFSM	5 <sup>1)</sup>	A
Power Dissipation at T <sub>A</sub> =65 <sup>°</sup> C	Ptot	200 <sup>1)</sup>	mW
Junction temperature	TJ	125	°C
Ambient Operating temperature Range	ТА	-65 to+125	ා ර
Storage Temperature Range	Tstg	-65 to+150	ා ර
1) Valid provided that leads at a distance of 4mm from case are kept at am	bient temperature		

### **ELECTRICAL CHARACTERISTICS**

	Symbols	Min.	Тур.	Max.	Units
Reverse breakdown voltage Tested with $100\mu A$ pulses	V(BR)R	30			V
Forward voltage Pulse Test $t_p < 300 \mu s, \delta < 2\%$ at $I = 0.1 mA$ , at $I = 10 mA$ , at $I = 10 mA$ , at $I = 30 mA$ , at $I = 10 0 mA$	VF VF VF VF VF			0.24 0.32 0.40 0.50 0.80	V V V V V
Leakage current VR=25V	IR			2.3	μA
Junction Capacitance at VR=1V ,f=1MHz	CJ			10	pF
Reverse recovery time Form IF=10mA,IR=10mA,IR=1mA	trr			4	ns
Thermal resistance junction to ambient Air	Reja			320	K/W

Ver.1.0